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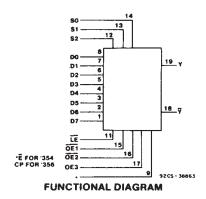
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File Number 1690



High-Speed CMOS Logic



8-Input Multiplexer/Register, 3-State

CD54/74HC/HCT354 — Transparent Data & Select Latches CD54/74HC/HCT356 — Edge-Triggered Data Flip-Flops Transparent Select Latches

Type Features:

- Buffered inputs
- 3-State Complementary Outputs
- Bus Line Driving Capability
- Typical propagation delay: V_{CC} = 5V, C_L = 15 pF, T_A = 25°C Data to Output (354) = 18 ns Clock to Output (356) = 22 ns

The RCA-CD54/74HC/HCT354 and CD54/74HC/HCT356 are data selectors/multiplexers that select one of eight sources. In both the HC/HCT354 and HC/HCT356 the data select bits S0, S1, and S2 are stored in transparent latches that are enabled by a low latch enable input, LE.

In the HC/HCT354 the data enable input, \overline{E} , controls transparent latches that pass data to the outputs when \overline{E} is high and latches in new data when \overline{E} is low.

In the HC/HCT356 the data is stored in edge-triggered flipflops that are triggered by a low-to-high clock transition.

In both types the three-state outputs are controlled by three output-enable inputs OE1, OE2, and OE3.

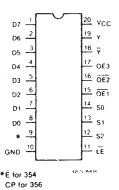
The CD54HC/HCT354/356 are supplied in 20-lead ceramic dual-in-line packages (F suffix). The CD74HC/HCT354/356 are supplied in 20-lead plastic dual-in-line plastic packages (E suffix). The CD54/74HC/HCT354/356 are also supplied in chip form (H suffix). The CD74HC/HCT354/356 are also available in plastic surface mounted packages (M suffix).

Family Features:

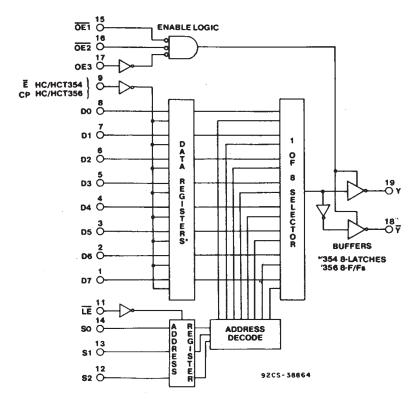
- Fanout (Over Temperature Range): Standard Outputs - 10 LSTTL Loads Bus Driver Outputs - 15 LSTTL Loads
- Wide Operating Temperature Range: CD74HC/HCT: -40 to +85° C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- Alternate Source is Philips/Signetics
- CD54HC/CD74HC Types: 2 to 6 V Operation High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC}; @ V_{CC} = 5 V
- CD54HCT/CD74HCT Types:

 4.5 to 5.5 V Operation
 Direct LSTTL Input Logic Compatibility
 V_{IL} = 0.8 V Max., V_{IH} = 2 V Min.

 CMOS Input Compatibility
 I₁ ≤ 1 μA @ V_{OL}, V_{OH}



TERMINAL ASSIGNMENT



Block Diagram

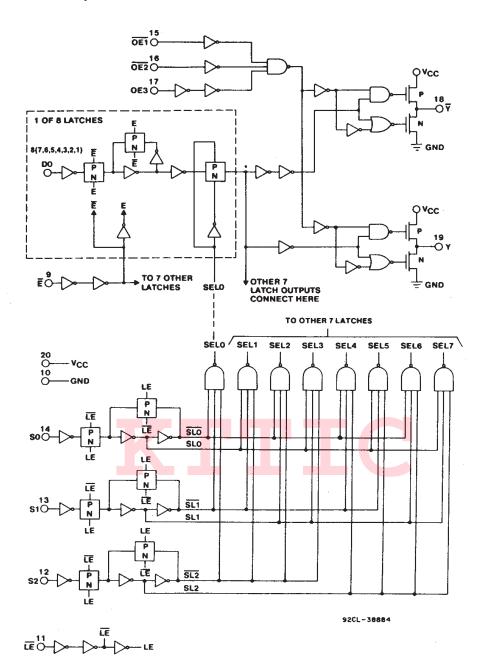
TRUTH TABLE

	Inputs									
s	elect	#	Enable Data 'HC354 'HCT354	Clock 'HC356 'HCT356		Outpu inable		Outp	outs	
S2	S1	SO	E	СР	ŌĒ1	ŌE2	OE3	Y	Y	
Х	Х	Х	Х	Х	Н	Х	Х	Z	Z	
X	Х	X	×	×	X	Н	Χ	Z	Z	
Х	Х	Х	×	×	X	Х	L.	Z	Z	
L	L	L	L		L	L	H	D0	D0	
L	L	L	н	HorL	L	L	H	DO _v	DO _n	
L	L	Н	L		L	L	Н	D1	D1	
L	L	Н	н	HorL	L	. L	H	D1 _n	D1 _n	
Ł	Н	L	L	~	L	L	Н	D2	D2	
L	Н	L	н	HorL	L	L	Н	D2 _n	D2 _n	
L	Н	Н	L	~	L	L	Н	D3	D3	
L	Н	F1	Н	HorL	L	Ł	Н	D3,	$D3_n$	
Н	L	L	L	~	L	L	Н	D4	D4	
н	L	L	н	HorL	L	Ł	H	D4 _n	D4 _n	
н	L	Н	L	~	L	Ł	H	D5	D5	
н	L	Н	н	HorL	L	L	Н	D5 ₀	$D5_n$	
н	Н	L	L		L	Ł	Н	D6	D6	
н	Н	L	н	Hort	L	Ĺ.	Н	D6,	D6 _n	
Н	Н	Н	L		L	L	H	D7	D7	
Н	H	Н	н	HorL	L	L	Н	D7,	D7.	

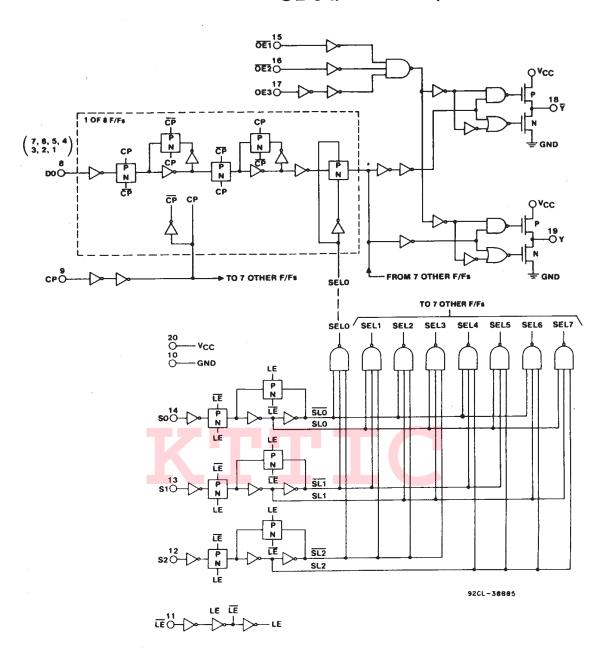
Notes

- H = high level (steady state)
- L = low level (steady state)

- L low level (steady state)
 X = irreflevant (any input, including transitions)
 Z = high-impedance state (off state)
 —= transition from low to high level
 D0 ... D7 = the level of steady-state inputs at inputs D0 through D7, respectively, at the time of the low-to-high clock transition in the case of HC356
- D0_n ... D7_n = the level of steady state inputs D0 through D7, respectively, before the most recent low-to-high transition of data control
- # This column shows the input address setup with LE low



HC/HCT354 Logic Diagram



HC/HCT356 Logic Diagram

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE, (Vcc)	
(Voltages referenced to ground)	
DC INPUT DIODE CURRENT, I_{IK} (FOR V, $<$ -0.5 V OR V, $>$ V _{CC} + 0.5V)	
DC OUTPUT DIODE CURRENT, I_{OK} (FOR V_{ν} < -0.5 V OR V_{ν} > 0.5 V +V	cc)
DC DRAIN CURRENT, PER OUTPUT (Io) (FOR -0.5 V < Vo < Vcc + 0.5	5V) ±35mA
DC V _{CC} OR GROUND CURRENT (I _{CC})	±70mA
POWER DISSIPATION PER PACKAGE (Pp):	,
For T _A = -40 to +60°C (PACKAGE TYPE E)	500 mW
For T _A = +60 to +85°C (PACKAGE TYPE E)	
For T _A = -55 to +100°C (PACKAGE TYPE F, H)	
For T _A = +100 to +125°C (PACKAGE TYPE F, H)	
For T _A = -40 to +70° C (PACKAGE TYPE M)	400 mW
For T _A = +70 to +125°C (PACKAGE TYPE M)	Derate Linearly at 6 mW/°C to 70 mW
OPERATING-TEMPERATURE RANGE (TA):	
PACKAGE TYPE F, H	55 to +125°C
PACKAGE TYPE E, M	40 to +85°C
STORAGE TEMPERATURE (Tsig)	+65 to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 in. (1.59 \pm 0.79 mm) from case for 10 s max.	+265°C
Unit inserted into a PC Board (min. thickness 1/16 in., 1.59 mm)	
with solder contacting lead tips only	+300°C

RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIM	ITS	LIAUTO
	MIN.	MAX.	UNITS
Supply-Voltage Range (For T _A = Full Package Temperature Range)			
CD54/74HC Types	2	6	
CD54/74HCT Types	4.5	5.5	\ \ \
DC Input or Output Voltage V _I , V _O	0	V _{CC}	V
Operating Temperature T _A :		- 00	<u> </u>
CD74 Types	-40	+85	°c
CD54 Types	-55	+125	
Input Rise and Fall Times t, tr			
at 2 V	0	1000	
at 4.5 V	l ŏ l	500	ns
at 6 V	ň	400	''3

^{*}Unless otherwise specified, all voltages are referenced to Ground.

KTTT (

CD54/74HC354, CD54/74HCT354 CD54/74HC356, CD54/74HCT356

STATIC ELECTRICAL CHARACTERISTICS

	CD74HC354/356/CD54HC354/356												CT354	1/356/	CD54	нст	354/3	CD74HCT354/356/CD54HCT354/356									
		TEST CONDITIONS			74HC/54HC 74HC TYPE TYPE			541 TY		TEST		1	CT/54 TYPE		74HCT TYPE		54HCT TYPE										
CHARACTERISTIC					+25° C		-40/ +85° C		-55/ +125° C		٧. ٧	V _{cc}	+25°C				0/ 5°C	-55/ +125°C		UNITS							
	v	mA	٧	Min	Тур	Max	Min	Max	Min	Max		_	Min	Тур	Max	Min	Max	Min	Max								
High-Level			2	1.5	_	-	1.5	_	1.5	_		4.5															
Input Voltage V _{IH}			4.5	3.15		-	3.15	_	3.15	_	_	to	2	_	-	2	-	2	_	٧							
			6	4.2	_		4.2	_	4.2	_		5.5															
Low-Level			2	-	_	0.5	_	0.5	_	0.5		4.5															
Input Voltage V _{IL}			4.5	-	_	1.35	_	1.35	-	1.35	-	to	-		0.8	–	0.8	_	0.8	٧							
			6	_	_	1.8	-	1.8	_	1.8		5.5															
High-Level	V _{IL}		2	1.9	-	-	1.9	_	1.9	_	V،L																
Output Voltage V _{он}	or	-0.02	4.5	4.4			4.4	_	4.4		or	4.5	4.4	–	_	4.4	-	4.4	-	v							
CMOS Loads	V _{irt}		6	5.9		-	5.9	-	5.9		V _{ire}																
	VıL										V _{tL}																
TTL Loads	or	-6	4.5	3.98	_	-	3.84		3.7	_	or	4.5	3.98	_	-	3.84	-	3.7	-	v							
(Bus Driver)	V _{n+}	-7.8	6	5.48	-	-	5.34		5.2	_	V _H																
Low-Level	VıL		2	-	-	0.1	-	0.1	-	0.1	ViL																
Output Voltage Vo.	or	0.02	4.5	-	_	0.1	_	0.1	-	0.1	or	4.5	-	_	0.1	-	0.1		0.1	v							
CMOS Loads	V _{#1}		6	-	_	0.1	_	0.1		0.1	V _H .																
	Vic										V _{IL}																
TTL Loads	or	6	4.5	-	-	0.26	-	0.33	-	0.4	or	4.5	_	-	0.26	-	0.33	-	0.4	v							
(Bus Driver)	V _{tH}	7.8	6		-	0.26	_	0.33	-	0.4	V _{IH}		ļ														
Input Leakage	V _{cc}										Any																
Current I	or		6	-		±0.1	_	±1	_	±1	Voltage Between	5.5	_	_	±0.1	-	±1		±1	μΑ							
	Gnd										V _{cc} & Gnd																
Quiescent	V _{cc}										V _{cc}																
Device	or	0	6	_	_	8	_	80	_	160	or	5.5	-	-	8	-	80	-	160	μA							
Current I _{cc}	Gnd										Gnd																
Additional Quiescent Device Current per input pin:		I		1	1		L			·	V _{cc} -2.1	4.5 to 5.5	_	100	360	_	450	-	490	μΑ							
1 unit load Δ lcc* 3-State Leakage Current loz	V _{IL} Or V _{IH}	V _o = V _{CC} or Gnd	6	-	_	±0.5	-	±5.0	-	±10	V _{IL} Of V _{IH}	5.5	_	_	<u>+</u> 0.5	-	±5.0	-	±10	μΑ							

^{*}For dual-supply systems theoretical worst case (V₁ = 2.4 V, V_{CC} = 5.5 V) specification is 1.8 mA.

HCT354 Input Loading Table

Input	Unit Loads*
D0-D7	0.50
S0, S1, S3	0.70
OE1, OE2	0.80
OE3	0.25
CE	0.25
Ē	0.60

^{*}Unit Load is ΔI_{CC} limit specified in Static Characteristic Chart, e.g., 360 μA max. @ 25°C.

HCT356 Input Loading Table

Input	Unit Loads*
D0-D7	0.50
S0, S1, S3	0.70
ŌĒ1, ŌĒ2	0.80
OE3	0.25
<u>LE</u>	0.25
СР	0.60

^{*}Unit Load is ΔI_{CC} limit specified in Static Characteristic Chart, e.g., 360 μ A max. @ 25° C.

SWITCHING CHARACTERISTICS (Vcc = 5 V, TA = 25°C, Input t, t, = 6 ns) - HC/HCT354

CHARACTERISTIC	CL	SYMBOL	TYP	ICAL	UNITS
OTATIA DE LA COLLEGIA	(pF)	SIMBOL	54/74HC	54/74HCT	OMITS
Propagation Delay Dn → Y, ♥	15	t _{PLH} , t _{PHL}	18	20	ns
Ē →Y, Ÿ	15	t _{PLH} , t _{PHL}	21	23	ns
Sn→ Y, Ÿ	15	t _{PLH} , t _{PHL}	22	25	ns
LE →Y, Ÿ	15	t _{PLH} , t _{PHL}	24	25	ns
Output Disabling Time	15	t _{PLZ} , t _{PHZ}	13	13, 16	ns
Output Enabling Time	15	tezl, tezh	12, 13	14	ns
Power Dissipation Capacitance*		C _{PD}	90	92	рF

^{*}CPD is used to determine the dynamic power consumption, per device.

PREREQUISITE FOR SWITCHING FUNCTION — HC/HCT354

				25	°C		-4	10°C te	o +85°	,C	-5	5°C to	+125	°C	
CHARACTERISTIC	SYMBOL	Vcc	Н	IC	H	CT	74	НС	74F	1CT	54	HC	54F	(CT	UNITS
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
E pulse width		2	80	l –	_	_	100	-	_	<u> </u>	120		_	 -	
	t _{PLH}	4.5	16		16	_	20	_	20		24	-	24	_	ns
	t _{PHL}	6	14	_	<u> </u>		17	_	_	_	20				
LE pulse width		2	80	_	-	_	100			_	120	_	-	<u> </u>	
	t _{PLH}	4.5	16	-	16		20	-	20	—	24	—	24	—	ns
	t _{PHL}	6	14			_	17			_	20				
Set Up Times		2	50	-	_		65	_	_	-	75			_	
Dn → Ē	tsu	4.5	10	-	10	-	13	-	13	<u> </u>	15	-	15	—	ns
		6	9			<u> </u>	11	-	—	_	13			_	
	·	2	50	 -		-	65		_	_	75	_	_	_	
Sn → LE	tsu	4.5	10	—	10	_	13	_	13	—	15	_	15	-	ns
		6	9			_	11				13			_	
Hold Times		2	45	-	_		55	_	_	_	70	_			
$Dn \rightarrow \overline{E}$	tн	4.5	9	-	9	—	11	_	11	-	14		14		ns
		6	8				9		_	<u> </u>	12		<u> </u>		
		2	45		_		55	_	-	_	70	_	_	_	
Sn → LE	ŧн	4.5	9	—	9	—	11		11.		14	-	14	_	ns
		6	8	<u> </u>	_		9	_	_	_	12	-	_	-	

 $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where:

f_i = input frequency,

C_L = output load capacitance.

V_{cc} = supply voltage

大変数値があった。では

SWITCHING CHARACTERISTICS (CL = 50 pF, Input t, t, = 6 ns) — HC/HCT354

				25	°C		-4	0° C to	+85°	C _		o°C to			
CHARACTERISTIC	SYMBOL	Vcc	Н	С	Н	CT	741	HC	74H	ICT	541	1C	54H		UNITS
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Propagation Delay,	t _{PLH}	2	<u> </u>	210	_		_	265	<u> </u>	_		315	—	—	
Dn → Y, \overline{Y}	tpHL	4.5	_	42		47	l —	53	-	59	_	63	—	71	ns
		6	_	36	_			45				54			
		2		250	_	_	_	315	-	l –		375	-	-	
$\overline{E} \rightarrow Y, \overline{Y}$	t _{PLH}	4.5	_	50	_	54	i —	63	-	68		75	-	81	ns
	t _{PHL}	6	_	43			l — _	54	_			64			
		2	1 -	260	_	-	-	325		-	-	390	_	-	
$Sn \rightarrow Y, \overline{Y}$	t _{PLH}	4.5	-	52	_	59	-	65	-	74	-	78	-	89	ns
• •	tpHL	6	-	44	_			55	<u> </u>			66		_	
		2	T	290	_	_	-	365	-	_		435	-		
LE → Y, ₹	t _{PLH}	4.5	-	58	-	63	-	73		79	-	87	-	94	ns
	tpHL	6	-	49	<u> </u>			62		<u> </u>	<u> </u>	74	<u> </u>		ļ
Output Disabling		2	_	155	Γ-	-	-	195	-	-	-	235	-		
Time		4.5	_	31	_	33	-	39	-	41	-	47	-	50	
OEn to Y, Y	telz	6	_	26			<u> </u>	33	_		_	40			ns
OE3 to Y, \overline{Y}	t _{PHZ}	2	_	155	Τ-	T -	_	195		-	-	235	-	-	""
	1,112	4.5	_	31	_	39	-	39	-	49	-	47	-	59	
0201011	Ì	6	_	26	_			33				40	1=		<u> </u>
Output Enabling		2	T	150		T	T -	190	_	-	-	225		-	
Time		4.5	_	30	-	34	-	38	-	43	-	45	-	51	
ŌĒn to Y, Ÿ	tezu	6	_	26	_	_	_	33				38	_		ns
02.11.0	t _{PZH}	2	1-	160	1 -	_	T-	200	_	-	-	240	_	-	1
OE3 to Y, \overline{Y}	ТРИ	4.5		32		34	_	40	_	43	-	48	-	51	
020107,7		6	_	27	_	_	-	34	_	_	<u> </u>	41		<u> </u>	<u> </u>
		2	1 -	60	1-	1 -		75	_	-	1 -	90	-	-	
Output	t _{TLH}	4.5		12	_	12	_	15	-	15	-	18	-	18	ns
Transition Time	tTHL	6	1 –	10	-		_	13	_	=	<u> </u>	15	_	 -	
Input				1								1		1	
Capacitance	C,		_	10	-	10	-	10	1 -	10	-	10	-	10	pF
•						1			 	 	 - -	 	-	+	+
3-state														1	_
Output	Co		-	20		20	-	20		20	-	20	-	20	pF
Capacitance								1							
Capacitation	-			1	Ш.	<u> </u>		1_			1	1	Щ.		1

SWITCHING CHARACTERISTICS (V_{CC} = 5 V, T_A = 25°C, Input t_r , t_r = 6 ns) — HC/HCT356

	CŁ	CYMBOL	TYP	ICAL	UNITS
CHARACTERISTIC	(pF)	SYMBOL	54/74HC	54/74HCT	
Propagation Delay CP → Y, Y	15	t _{PLH} , t _{PHL}	22	22	ns
Sn→Y, ▼	15	t _{PLH} , t _{PHL}	22	25	ns
LE →Y, Ÿ	15	t _{PLH} , t _{PHL}	24	25	ns
Output Disabling Time	15	tplz, tpHZ	13	13, 15	ns
Output Enabling Time	15	t _{PZL} , t _{PZH}	12, 13	14	ns
Power Dissipation Capacitance*		CPD	51	52	pF

*CPD is used to determine the dynamic power consumption, per device

 $P_D = V_{CC}^2 f_i(C_{PD} + C_L)$ where:

f. = input frequency.

C_L = output load capacitance

V_{cc} = supply voltage.

PREREQUISITE FOR SWITCHING FUNCTION — HC/HCT356

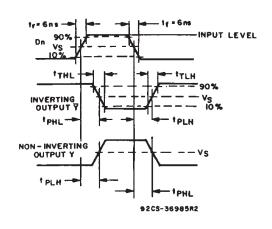
			1.	25	°C		-4	0°C t	o +85°	°C	-5	5°C to	+125	°C	
CHARACTERISTIC	SYMBOL	Vcc	Н	C	Н	CT.	74	HC	741	1CT	54	НС	54F	1CT	UNITS
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.]
CP Pulse Width	t _{PLH}	2	80	-	_	_	100	_		_	120	<u> </u>	<u> </u>	_	
		4.5	16	-	20		20	-	25	_	24	_	30	_	ns
	t _{PHL}	6	14		L <u> —</u>	_	17			l —	20	_]
LE Pulse Width		2	80	_	_		100	_	_		120	_	_	_	
	t _{PLH}	4.5	16	-	20	_	20	_	25		24		30	_	ns
	t _{PHL}	6	14	_			17	_	_	_	20	_	_	 	
Set Up Times		2	5	-	_	_	5	_	_		5	_		_	
Dn → CP	t _{su}	4.5	5		7	_	5	_	9	—	5	_	11		ns
		6	5	<u> </u>	_		5	_	i	_	5		_	_	
		2	5		_	_	5	<u> </u>	_	_	5			_	
Sn → LĒ	t _{su}	4.5	5	_ [7	_	5	_	9	_	5	_	11	-	ns
		6	5	-		_	5	-	_	_	5	-	_		
Hold Times		2	45	-	_		55			_	70		_		
Dn → CP	t _n	4.5	9	-	9	_	.11		11	_	14	-	14	_	ns
		6	8		_	_	9	_	_		12	_			
		2	60	_	_		75		_	_	90	_	_	_	
Sn → LE	th	4.5	12	-	12		15	- 1	15	_	18	_	18	_	ns
	<u> </u>	6	10		_	_	13	_	_	_	15				

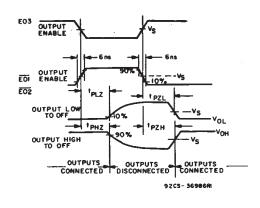
SWITCHING CHARACTERISTICS (CL - 50 pF, Input t, t, = 6 ns) - HC/HCT356

SYMBOL	Vcc	25°C					O°C t	0 .00	-	-5												
J. M.D.C.			Į H	C	Н	СТ	74	HC	74H	ICT	54	HC	54F	ICT	UNITS							
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	1								
	2	-	255	_	_		320		_		385	_	_									
1	4.5	_	51		51	_	64	_	64		77	_	77	ns								
tpHL	6		43	_		_	54			-	65	_	_									
	2	_	260	_		_	325	_	_	_	390	_	_									
	4.5	—	52		59	_	65	_	74	_	78		89	ns								
IPHL.	6	-	44	_	_	_	55	-	_	—	66	_	—									
	2	-	290	_		_	365	_	<u> </u>		435		_									
	4.5	-	58		63		73	_	79	-	87		94	ns								
IPHL	6	<u> </u>	49		_	_	62	_	_	_	74		—									
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fr. u	_	-	60		_	_	75	-	-	_	90	-	-									
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C,			10		10	_	10	-	10		10		10	pF								
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CD54/74HC354, CD54/74HCT354 CD54/74HC356, CD54/74HCT356





	54/74HC	54/74HCT
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Vs	50% V _{CC}	1.3 V

Fig. 1 — Transition times and propagation delay times.

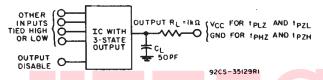


Fig. 2 — Three-state propagation delay test circuit.

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